## NSN 5961-01-187-2071

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View Online at https://aerobasegroup.com/nsn/5961-01-187-2071 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Burn in and hermetically sealed case and quality assurance level tx and reverse polarity **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.3 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 11.05 amperes all primaries horsepower metric and 2.90 amperes repetitive peak forward current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Test Data Document:** 81349-mil-prf-19500 standard (includes industry or association standards, individual manufactureer standards, etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.